

# 1200V 75A Insulated Gate Bipolar Transistor

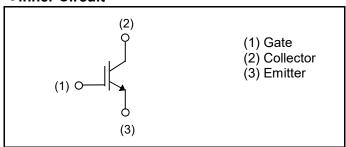
V <sub>CES</sub>	1200V
I <sub>C (Nominal)</sub>	75A
V <sub>CE(sat) (Typ.)</sub>	1.7V
Max. Possible Chips per Wafer	152pcs

# ● Outline Wafer

#### Features

- 1) Trench Light Punch Through Type
- 2) Low Collector Emitter Saturation Voltage
- 3) Short Circuit Withstand Time 10µs

## ●Inner Circuit



## Application

General Inverter

for Industrial Use

## Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Collector - Emitter Voltage, T <sub>j</sub> = 25°C	V <sub>CES</sub>	1200	V
Gate - Emitter Voltage	$V_{GES}$	±30	V
Collector Current	I <sub>C</sub> <sup>*1</sup>	*1)	Α
Pulsed Collector Current	I <sub>CP</sub> *2	225	Α
Operating Junction Temperature	T <sub>j</sub>	-40 to +175	°C

<sup>\*1</sup> Depending on thermal properties of assembly

<sup>\*2</sup> Pulse width limited by  $T_{\text{jmax.}}$ 

## ●Design Assurance

Parameter Symbol Conditions		Values			Unit	
raiailletei	Symbol	Conditions	Min.	Тур.	Max.	Offic
		$V_{CC} \le 600V$ ,				
Short Circuit Withstand Time	t <sub>sc</sub> *3	$V_{CC} \le 600V$ , $V_{GE} = 15V$ , $T_j = 25^{\circ}C$	10	-	-	μs
		T <sub>j</sub> = 25°C				
		$V_{CC} \le 600V$ ,				
Short Circuit Withstand Time	$t_{sc}^{*3}$	V <sub>GE</sub> = 15V, T <sub>i</sub> = 150°C	8	-	-	μs
		T <sub>j</sub> = 150°C				
		$I_C = 225A, V_{CC} = 1050V,$	<u> </u>			
Reverse Bias Safe Operating Area	RBSOA*3	$I_{C} = 225A, V_{CC} = 1050V,$ $V_{P} = 1200V, V_{GE} = 15V,$ $R_{G} = 50\Omega, T_{j} = 175^{\circ}C$	FULL SQUARE		-	
7,1104		$R_G = 50\Omega, T_j = 175^{\circ}C$				

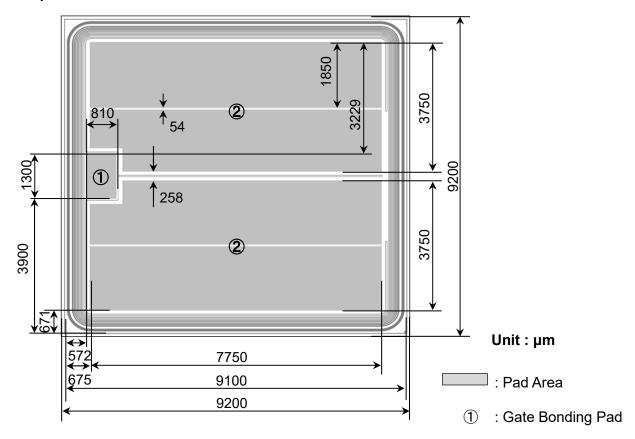
<sup>\*3</sup> Design assurance without measurement

# ●Electrical Characteristics (at T<sub>j</sub> = 25°C unless otherwise specified)

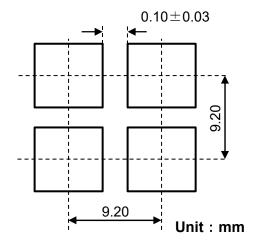
Doromotor	Cumbal	Symbol Conditions		Values			
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Collector - Emitter Breakdown Voltage	BV <sub>CES</sub>	$I_{C} = 10 \mu A, V_{GE} = 0 V$	1200	-	-	V	
Collector Cut - off Current	I <sub>CES</sub>	V <sub>CE</sub> = 1200V, V <sub>GE</sub> = 0V	ı	ı	10	μΑ	
Gate - Emitter Leakage Current	I <sub>GES</sub>	$V_{GE} = \pm 30V$ , $V_{CE} = 0V$	ı	ı	±500	nA	
Gate - Emitter Threshold Voltage	$V_{\text{GE(th)}}$	V <sub>CE</sub> = 5V, I <sub>C</sub> = 11.1mA	5.0	6.0	7.0	V	
Collector - Emitter Saturation Voltage	V <sub>CE(sat)</sub> *3	$I_{C} = 75A, V_{GE} = 15V,$ $T_{j} = 25^{\circ}C$ $T_{j} = 175^{\circ}C$	-	1.7 2.2	2.1	V	
Input Capacitance	C <sub>ies</sub>	V <sub>CE</sub> = 30V,	-	6250	-		
Output Capacitance	C <sub>oes</sub>	$V_{GE} = 0V$ ,	-	315	-	pF	
Reverse transfer Capacitance	$C_{res}$	f = 1MHz	ı	32	ı		
Total Gate Charge	$Q_g$	V <sub>CE</sub> = 500V,	ı	202	ı		
Gate - Emitter Charge	$Q_ge$	I <sub>C</sub> = 75A,	-	57	-	nC	
Gate - Collector Charge	$Q_{gc}$	V <sub>GE</sub> = 15V	-	75	-		

<sup>\*3</sup> Design assurance without measurement

## **●Chip Information**



② : Emitter Bonding Pad



Wafer Size	150mm
Wafer Thickness	0.14±0.01mm
Chip Size	9.20mm×9.20mm
Cut Line Width	0.10±0.03mm
Top Side Metallization	AlSiCu:4.4µm
Back Side Metallization	Ti/Ni:0.4μm/Au:0.05μm
Passivation	Polyimide

Backside: Collector

### •Further Electrical Characteristics

Switching characteristics and thermal properties are depending strongly on module design and mounting technology and can therefore not be specified for a bare die.

This chip data sheet refers to the device data sheet	-
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Technology qualified in TO-247N package.

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